

Vishay General Semiconductor

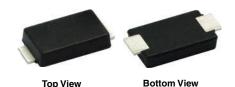
RoHS COMPLIANT

HALOGEN

FREE

Surface Mount TRANSZORB® Transient Voltage Suppressors

SlimSMATM



DO-221AC

Top View

PRIMARY CHARACTERISTICS							
V _{BR} 6.4 V to 24.5 V							
V_{WM}	5.0 V to 20 V						
P _{PPM} (10 x 1000 μs)	600 W						
P _{PPM} (8 x 20 μs)	4000 W						
P _D at T _M = 55 °C	6 W						
T _J max.	175 °C						
Polarity	Uni-directional						
Package	DO-221AC (SlimSMA)						

TYPICAL APPLICATIONS

Use in sensitive electronics protection against voltage transients induced by inductive load switching and lighting on ICs, MOSFET, signal lines of sensor units for consumer, computer, industrial, and telecommunication.

FEATURES

- Very low profile typical height of 0.95 mm
- Ideal for automated placement
- Uni-directional only
- · Excellent clamping capability
- Peak pulse power:
 - 600 W (10/1000 µs)
 - 4 kW (8/20 µs)
- ESD capability: IEC 61000-4-2 level 4
- 15 kV (air)
- 8 kV (contact)
- Meets MSL level 1, per J-STD-020, LF maximum peak of
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

MECHANICAL DATA

Case: DO-221AC (SlimSMA)

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Terminals: Matte tin plated leads, solderable J-STD-002 and JESD22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: Color band denotes cathode end

MAXIMUM RATINGS (T _A = 25 °C, unless otherwise noted)								
PARAMETER	SYMBOL	VALUE	UNIT					
Dock pulse power dissination	with a 10/1000 µs waveform	P _{PPM} ⁽¹⁾	600	w				
Peak pulse power dissipation	with a 8/20 µs waveform	FPPM (1)	4000					
Peak pulse current	with a 10/1000 µs waveform	I _{PPM} ⁽¹⁾	See next table	۸				
	with a 8/20 µs waveform	IPPM (")	See flext table	A				
Power dissipation	T _M = 55 °C	P _D ⁽²⁾ 6		w				
rower dissipation	T _A = 25 °C	P _D ⁽³⁾	1.0] vv				
Storage temperature range	T _{STG}	-65 to +175	°C					
Operating junction temperature range	TJ	-55 to +175						

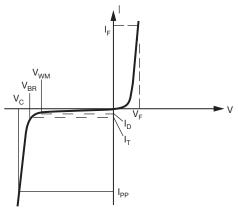
- (1) Non-repetitive current pulse, per fig. 3 and derated above $T_A = 25$ °C per fig. 2.
- (2) Power dissipation mounted on infinite heatsink
- (3) Power dissipation mounted on minimum recommended pad layout



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INDEX OF SYMBOLS					
SYMBOL	PARAMETER				
V _{WM}	Stand-off voltage				
V _{BR}	Breakdown voltage				
V _C	Clamping voltage				
I _D	Leakage current at V _{WM}				
I _{PP}	Peak pulse current				
αΤ	Voltage temperature coefficient				
V _F	Forward voltage drop				
R _D	Dynamic resistance				



Zener Voltage Regulator

ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)															
		BREAKDOWN		STAND-OFF	MAXIMUM		V _C AT I _{PP} R _D ⁽²⁾		V _C AT I _{PP}		R _D ⁽²⁾				
DEVICE TYPE	DEVICE MARKING	VC	DLTAG R AT I _T	E	VOLTAGE V _{WM}	REVERSE LEAKAGE I _D AT V _{WM} ⁽³⁾		10/1000 µs			8/20 μs			αT ⁽³⁾	
	CODE	MIN.	MAX.			25 °C	85 °C		MAX.			MAX.			MAX.
		1	V	mA	V	μ	Α	٧	٧	Α	Ω	٧	Α	Ω	10 ⁻⁴ /°C
SMA6F5.0A	6AE	6.40	7.07	10	5	150	375	5.0	9.2	68.0	0.031	13.4	298	0.021	5.7
SMA6F6.0A	6AG	6.70	7.41	10	6	600	1500	6.0	9.5	63.2	0.033	13.7	290	0.022	5.9
SMA6F6.5A	6AK	7.20	7.96	10	6.5	100	250	6.5	10.2	58.8	0.038	14.5	276	0.024	6.1
SMA6F7.5A	6AP	8.33	9.21	1	7.5	50	125	7.5	11.8	50.8	0.051	17.0	235	0.033	6.5
SMA6F8.0A	6AR	8.89	9.83	1	8.0	20	50	8.0	12.8	46.9	0.063	18.2	220	0.038	7.0
SMA6F8.5A	6AT	9.4	10.4	1	8.5	20	50	8.5	13.3	45.1	0.064	18.7	205	0.040	7.3
SMA6F10A	6AX	11.1	12.3	1	10	1.0	5.0	10	15.7	38.2	0.089	19.6	184	0.040	7.8
SMA6F11A	6AZ	12.2	13.5	1	11	1.0	5.0	11	17.2	34.8	0.107	21.5	172	0.047	8.1
SMA6F12A	6BE	13.3	14.7	1	12	0.2	1.0	12	18.8	31.9	0.128	23.5	157	0.056	8.3
SMA6F12AHD	6BF	13.2	14.3	1	12	0.2	1.0	12	18.5	32.4	0.130	22.9	157	0.055	8.4
SMA6F13A	6BG	14.4	15.9	1	13	0.2	1.0	13	20.4	29.4	0.153	23.9	147	0.064	8.4
SMA6F15A	6BM	16.7	18.5	1	15	0.2	1.0	15	23.6	25.4	0.201	27.7	123	0.075	8.8
SMA6F16A	6BP	17.8	19.7	1	16	0.2	1.0	16	25.2	23.8	0.229	29.5	119	0.082	8.8
SMA6F17A	6BR	18.9	20.9	1	17	0.2	1.0	17	26.7	22.5	0.259	31.4	111	0.095	9.0
SMA6F18A	6BT	20.0	22.1	1	18	0.2	1.0	18	28.3	21.2	0.292	33.2	102	0.109	9.2
SMA6F20A	6BV	22.2	24.5	1	20	0.2	1.0	20	31.4	19.1	0.361	36.8	93	0.132	9.4

Notes

⁽³⁾ To calculate V_{BR} vs. junction temperature, use following formula: V_{BR} at $T_J = V_{BR}$ at 25 °C x (1 + α T x (T_J - 25))

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)							
PARAMETER SYMBOL VALUE UNIT							
Typical thermal resistance, junction to ambient	R _{0JA} (1)	150	°C/W				
Typical thermal resistance, junction to mount	R _{0JM} ⁽²⁾	20	°C/W				

Notes

⁽¹⁾ Pulse test: $t_p \le 50 \text{ ms}$

 $^{^{(2)}}$ To calculate maximum clamping voltage at other surge currents, use following formula: V_{CL} max. = $R_D \times I_{PP} + V_{BR}$ max.

⁽¹⁾ Mounted on minimum recommended pad layout

⁽²⁾ Mounted on infinite heatsink



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IMMUNITY TO STATIC ELECTRICAL DISCHARGE TO THE FOLLOWING STANDARDS ($T_A = 25~^{\circ}\text{C}$ unless otherwise noted)								
STANDARD	TEST TYPE TEST CONDITIONS SYMBOL CLASS VALUE							
IEC 61000-4-2	Human body model (contact mode)	$C = 150 \text{ pF}, R = 330 \Omega$	V	4	> 8 kV			
IEC 61000-4-2	Human body model (air discharge mode)	C = 150 pr, h = 550 \$2	V _C	4	> 15 kV			

ORDERING INFORMATION (Example)								
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE				
SMA6F5.0A-M3/6A	0.032	6A	3500	7" diameter plastic tape and reel				
SMA6F5.0A-M3/6B	0.032	6B	14 000	13" diameter plastic tape and reel				

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

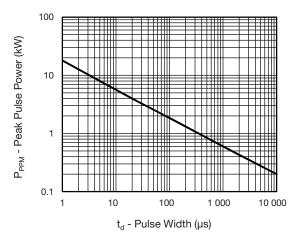


Fig. 1 - Peak Pulse Power Rating Curve

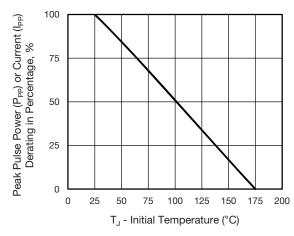


Fig. 2 - Pulse Power or Current vs. Initial Junction Temperature

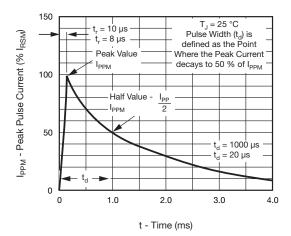
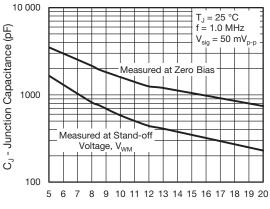


Fig. 3 - Pulse Waveform



V_{WM} - Reverse Stand-Off Voltage (V)

Fig. 4 - Typical Junction Capacitance





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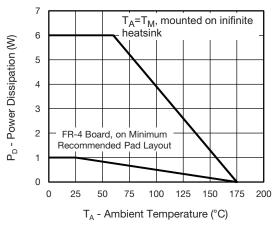


Fig. 5 - Power Dissipation Derating Curve

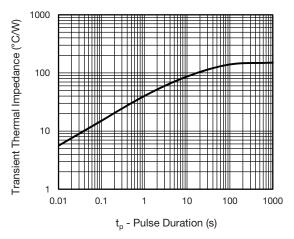
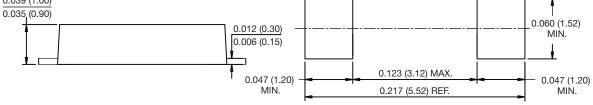


Fig. 6 - Typical Transient Thermal Impedance

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

DO-221AC (SlimSMA) Cathode Band 0.057 (1.45) 0.106 (2.70) 0.049 (1.25) 0.098 (2.50) 0.171 (4.35) 0.047 (1.20) Typ.: 0.019 (0.48) 0.163 (4.15) 0.030 (0.75) 0.211 (5.35) 0.199 (5.05) **Mounting Pad Layout** 0.039 (1.00) 0.035, (0.90)





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